## Product Summary

| BV ${ }_{\text {dss }}$ | $\mathrm{R}_{\mathrm{DS} \text { (ON) }} \mathrm{Max}$ | $\begin{gathered} \mathrm{I}_{\mathrm{D}} \operatorname{Max} \\ \mathrm{~T}_{\mathrm{C}}=+25^{\circ} \mathrm{C} \end{gathered}$ |
| :---: | :---: | :---: |
| -40V | $25 \mathrm{~m} \Omega$ @ $\mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V}$ | -40A |
|  | $45 \mathrm{~m} \Omega @ \mathrm{~V}_{\mathrm{GS}}=-4.5 \mathrm{~V}$ | -30A |

## Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Reverse-Polarity Protection
- Power-Management Functions
- DC-DC Converters


## Features and Benefits

- Rated to $+175^{\circ} \mathrm{C}$-Ideal for High Ambient Temperature Environments
- Low RDS(ON)—Ensures Minimal On-State Losses
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33\% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free \& Fully RoHS Compliant (Notes 1 \& 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)


## Mechanical Data

- Case: PowerDI ${ }^{\circledR} 3333-8$ (SWP) (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.072 grams (Approximate)



## Ordering Information (Note 5)

| Part Number | Case | Packaging |
| :---: | :---: | :---: |
| DMPH4025SFVWQ-7 | PowerDI3333-8 (SWP) (Type UX) | 2000/Tape \& Reel |
| DMPH4025SFVWQ-13 | PowerDI3333-8 (SWP) (Type UX) | 3000/Tape \& Reel |

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) \& 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen-and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain $<900 \mathrm{ppm}$ bromine, $<900 \mathrm{ppm}$ chlorine ( $<1500 \mathrm{ppm}$ total $\mathrm{Br}+\mathrm{Cl}$ ) and <1000ppm antimony compounds
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## Marking Information



[^0]PowerDI is a registered trademark of Diodes Incorporated.

DMPH4025SFVWQ

Maximum Ratings $@_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic |  | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Drain-Source Voltage |  | $V_{\text {DSS }}$ | -40 | V |
| Gate-Source Voltage |  | $\mathrm{V}_{\text {GSS }}$ | $\pm 20$ | V |
| Continuous Drain Current (Note 6) VGS =-10V | $\begin{aligned} & \mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{A}}=+70^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | ID | $\begin{array}{r} \hline-8.7 \\ -7.3 \\ \hline \end{array}$ | A |
|  | $\begin{aligned} & \mathrm{T} \mathrm{C}=+25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=+70^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ | $\begin{gathered} \mathrm{ID}_{\mathrm{D}} \\ \text { (Package Limit) } \\ \hline \end{gathered}$ | $\begin{aligned} & \hline-40 \\ & -33 \\ & \hline \end{aligned}$ | A |
| Pulsed Drain Current (10 $\mu$ s Pulse, Duty Cycle = 1\%) |  | IDM | -80 | A |
| Maximum Continuous Body Diode Forward Current |  | Is | -3 | A |
| Pulsed Source Current (10 ${ }^{\text {s P Pulse, Duty Cycle = 1\%) }}$ |  | ISM | -80 | A |
| Avalanche Current, $\mathrm{L}=0.3 \mathrm{mH}$ |  | $\mathrm{I}_{\text {AS }}$ | -23 | A |
| Avalanche Energy, $\mathrm{L}=0.3 \mathrm{mH}$ |  | $\mathrm{E}_{\text {AS }}$ | 82 | mJ |

Thermal Characteristics $\left(@ T_{A}=+25^{\circ} \mathrm{C}\right.$, unless otherwise specified.)

| Characteristic |  | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Total Power Dissipation (Note 6) | $\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ | PD | 2.3 | W |
|  | $\mathrm{T}_{\mathrm{C}}=+25^{\circ} \mathrm{C}$ |  | 60 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | ReJa | 53 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction to Case (Note 6) |  | Reлc | 2.5 |  |
| Operating and Storage Temperature Range |  | TJ, $\mathrm{TSTG}^{\text {d }}$ | -55 to +175 | ${ }^{\circ} \mathrm{C}$ |

Electrical Characteristics ( $@ \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS (Note 7) |  |  |  |  |  |  |
| Drain-Source Breakdown Voltage | BV ${ }_{\text {DSS }}$ | -40 | - | - | V | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-250 \mu \mathrm{~A}$ |
| Zero Gate Voltage Drain Current | IDSS | - | - | -1 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{DS}}=-40 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ |
| Gate-Source Leakage | IGss | - | - | $\pm 100$ | nA | $\mathrm{V}_{\mathrm{GS}}= \pm 20 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}$ |
| ON CHARACTERISTICS (Note 7) |  |  |  |  |  |  |
| Gate Threshold Voltage | $\mathrm{V}_{\mathrm{GS}}(\mathrm{TH})$ | -0.8 | - | -1.8 | V | $\mathrm{V}_{\mathrm{DS}}=\mathrm{V}_{\mathrm{GS}}, \mathrm{I}_{\mathrm{D}}=-250 \mu \mathrm{~A}$ |
| Static Drain-Source On-Resistance | RDS(ON) | - | 18 | 25 | $\mathrm{m} \Omega$ | $\mathrm{V}_{\mathrm{GS}}=-10 \mathrm{~V}, \mathrm{ID}_{\mathrm{D}}=-30 \mathrm{~A}$ |
|  |  | - | 23 | 45 |  | $\mathrm{V}_{\mathrm{GS}}=-4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-15 \mathrm{~A}$ |
| Diode Forward Voltage | $\mathrm{V}_{\text {SD }}$ | - | - | -1 | V | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{IS}=-1 \mathrm{~A}$ |
| DYNAMIC CHARACTERISTICS (Note 8) |  |  |  |  |  |  |
| Input Capacitance | $\mathrm{C}_{\text {iss }}$ | - | 1918 | - | pF | $\begin{aligned} & V_{D S}=-20 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \\ & f=1 \mathrm{MHz} \end{aligned}$ |
| Output Capacitance | Coss | - | 390 | - | pF |  |
| Reverse Transfer Capacitance | Crss | - | 151 | - | pF |  |
| Gate Resistance | $\mathrm{R}_{\mathrm{g}}$ | - | 5.76 | - | $\Omega$ | $\mathrm{V}_{\mathrm{DS}}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |
| Total Gate Charge (VGS $=-4.5 \mathrm{~V}$ ) | $\mathrm{Q}_{\mathrm{g}}$ | - | 19.6 | - | nC | $V_{D S}=-20 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=-3 \mathrm{~A}$ |
| Total Gate Charge (VGS $=-10 \mathrm{~V}$ ) | $\mathrm{Q}_{\mathrm{g}}$ | - | 38.6 | - | nC |  |
| Gate-Source Charge | $\mathrm{Q}_{\mathrm{gs}}$ | - | 3.7 | - | nC |  |
| Gate-Drain Charge | $\mathrm{Q}_{\mathrm{gd}}$ | - | 7.3 | - | nC |  |
| Turn-On Delay Time | tD(ON) | - | 4.8 | - | ns | $\begin{aligned} & V_{D D}=-20 \mathrm{~V}, V_{G S}=-10 \mathrm{~V}, \\ & I_{D}=-3 A \end{aligned}$ |
| Turn-On Rise Time | $\mathrm{t}_{\mathrm{R}}$ | - | 14.2 | - | ns |  |
| Turn-Off Delay Time | $\mathrm{t}_{\text {(IOFF) }}$ | - | 72.2 | - | ns |  |
| Turn-Off Fall Time | $\mathrm{t}_{\mathrm{F}}$ | - | 35.9 | - | ns |  |

Notes: 6. Device mounted on FR-4 substrate PC board, 2 oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

$\mathrm{V}_{\mathrm{DS}}$, DRAIN-SOURCE VOLTAGE (V)
Figure 1. Typical Output Characteristic


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage


Figure 5. Typical On-Resistance vs. Drain Current and Temperature



Figure 4. Typical Transfer Characteristic


Figure 6. On-Resistance Variation with Temperature

DMPH4025SFVWQ


Figure 7. On-Resistance Variation with Temperature



Figure 11. Gate Charge


Figure 8. Gate Threshold Variation vs. Junction Temperature


Figure 10. Typical Junction Capacitance


DMPH4025SFVWQ


Figure 13. Transient Thermal Resistance

DMPH4025SFVWQ

Package Outline Dimensions
Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI3333-8 (Type UX)



## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

## PowerDI3333-8 (Type UX)



| Dimensions | Value (in mm) |
| :---: | :---: |
| $\mathbf{C}$ | 0.650 |
| $\mathbf{X}$ | 0.420 |
| $\mathbf{X 1}$ | 0.420 |
| $\mathbf{X 2}$ | 0.230 |
| $\mathbf{X 3}$ | 2.370 |
| $\mathbf{Y}$ | 0.700 |
| Y1 | 1.850 |
| Y2 | 2.250 |
| Y3 | 3.700 |
| $\mathbf{Y 4}$ | 0.540 |

## IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

## LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:
A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2018, Diodes Incorporated
www.diodes.com

## X-ON Electronics

Largest Supplier of Electrical and Electronic Components
Click to view similar products for MOSFET category:
Click to view products by Diodes Incorporated manufacturer:
Other Similar products are found below :
614233C 648584F IRFD120 JANTX2N5237 FCA20N60_F109 FDZ595PZ 2SK2545(Q,T) 405094E 423220D TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C IPP110N20N3GXK BUK954R8-60E NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) DMN1017UCP3-7 EFC2J004NUZTDG ECH8691-TL-W FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE221 NTE222 NTE2384 NTE2941 NTE2945 NTE2946 NTE2960 NTE2969 NTE2976 NTE6400A NTE2916 NTE2956 NTE2911 DMN2080UCB4-7 TK10A80W,S4X(S STF35N65DM2 STW70N60DM6-4 SSM6P54TU,LF SSM6P69NU,LF DMP22D4UFO-7B DMN1006UCA6-7 DMN16M9UCA6-7


[^0]:    PW1 = Product Type Marking Code
    YYWW = Date Code Marking
    YY = Last Two Digits of Year (ex: $17=2017$ )
    WW = Week Code (01 to 53)

